

MOLDED THIN FILM CONTAINING SEMICONDUCTOR CRYSTAL PARTICLE, AND ITS USE

Patent number: JP2003138033

Publication date: 2003-05-14

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Classification:

- international: *C08J5/18; C08K9/04; C08L101/00; C09K11/06; G02B1/10; G02B1/11; G11B7/24; H05B33/14; H05B33/20; C08J5/18; C08K9/00; C08L101/00; C09K11/06; G02B1/10; G11B7/24; H05B33/12; H05B33/14; (IPC1-7): C08J5/18; C08K9/04; C08L101/00; C09K11/06; G02B1/10; G02B1/11; G11B7/24; H05B33/14; H05B33/20*

- european:

Application number: JP20010336119 20011101

Priority number(s): JP20010336119 20011101

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Abstract of JP2003138033

PROBLEM TO BE SOLVED: To provide a molded thin film excellent in transparency, surface hardness and antistatic properties, and having excellent characteristics, such as luminous characteristics, light absorption saturation characteristics and ultraviolet absorption characteristics, and a high refractive index. **SOLUTION:** The molded thin film contains semiconductor crystal particles having a polyalkylene glycol residue bonded to the surface through an amino group.

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